

#### **Features**

- Compatible with MBI5168 in package and electrical characteristics
- Exploit Share-I-O<sup>™</sup> technique to provide two operation modes: Normal Mode with the same functionality as MB5168, Current Adjust Mode to program output current gain
- 8 constant-current output channels
- Output current adjustable through an external resistor
- Constant output current range: 5 -120 mA
- Excellent output current accuracy, between channels < ±3% (max.), and between ICs <  $\pm 6\%$  (max.).
- Constant output current invariant to load voltage change
- Fast response of output current, OE (min.): 200 ns @l<sub>out</sub> < 60mA OE (min.): 400 ns @lout = 60~100mA
- 25MHz clock frequency
- Schmitt trigger input
- 3.3V~ 5V supply voltage
- 256-step run-time programmable output current gain suitable for white balance application
- Optional for "Pb-free & Green" Package

Dual In-Line Package
A THERE A
P-DIP16-300-2.54 Weight : 1.02g
Small Outline Package
- THARAM
SOP16-150-1.27 Weight : 0.13g
Wide-body SOP
- THE
a Barres.
SOP16-300-1.27 Weight : 0.37g
SOP16-300-1.27 Weight : 0.37g

Current /	Conditions	
Between Channels	Between ICs	Conditions
< ±3%	< ±6%	$    I_{OUT} = 10 \sim 100 \text{ mA}, \\     V_{DS} = 0.8 \text{V}, \text{ V}_{DD} = 5.0 \text{V}                                   $

#### **Product Description**

MBI5170 succeeds MBI5168 and also exploits **PrecisionDrive**<sup>™</sup> technology to enhance its output characteristics. Furthermore, MBI5170 uses the idea of **Share-I-O**<sup>™</sup> technique to make MBI5170 backward compatible with MBI5168 in both package and electrical characteristics and extend its functionality for run-time LED current gain control in LED display systems.

MBI5170 contains an 8-bit Shift Register and an 8-bit Output Latch, which convert serial input data into parallel output format. At MBI5170 output stages, eight regulated current ports are designed to provide uniform and constant current sinks with small skew between ports for driving LED's with a wide range of forward voltage (Vf) variations. Users may adjust the output current from 5 mA to 120 mA with an external resistor  $R_{ext}$ , which gives users flexibility in controlling the light intensity of LED's. MBI5170 guarantees to endure maximum 17V at the output ports. Besides, the high clock frequency up to 25 MHz also satisfies the system requirements of high volume data transmission.

By means of the **Share-I-O<sup>TM</sup>** technique, MBI5170 adds new functionality on the pins LE and  $\overrightarrow{OE}$  of MBI5168 to provide an additional function, Current Gain Control, without any extra pins. Thus, MBI5170 could be a drop-in replacement of MBI5168. The printed circuit board originally designed for MBI5168 may be also applied to MBI5170. In MBI5170 there are two operation modes and three phases: Normal Mode phase, Mode Switching transition phase, and Current Adjust Mode phase. The signal on the multi-function pin  $\overrightarrow{OE}$ /SW would be monitored. Once a one-clock-wide short pulse appears on the pin  $\overrightarrow{OE}$ /SW, MBI5170 would enter the Mode Switching phase. At this moment, the voltage level on the pin LE/MOD/CA is used for determining the next mode to which MBI5170 is going to switch.

In the Normal Mode phase, MBI5170 has similar functionality to MBI5168. The serial data could be transferred into MBI5170 via the pin SDI, shifted in the Shift Register, and go out via the pin SDO. The LE/MOD/CA can latch the serial data in the Shift Register to the Output Latch.  $\overline{OE}$ /SW would enable the output drivers to sink current.

On the other hand, the Current Adjust Mode phase allows users to adjust the output current level by setting a run-time programmable Configuration Code. The code is sent into MBI5170 via the pin SDI. The positive pulse of LE/MOD/CA would latch the code in the Shift Register into a built-in 8-bit Configuration Latch, instead of the Output Latch. The code would affect the voltage at the terminal R-EXT and control the output current regulator. The output current could be adjusted finely by a current gain ranging from (1/12) to (127/128) in 256 steps. Hence, the current skew between IC's can be compensated within less than 1% and this feature is suitable for white balancing in LED color display panels.

#### **Pin Assignment**



## **Terminal Description**

Pin No.	Pin Name	Function
1	GND	Ground terminal for control logic and current sinks
2	SDI	Serial-data input to the Shift Register
3	CLK	Clock input terminal for data shift on rising edge
4	LE/MOD/CA	<b>Output channel data strobe input terminal:</b> in the Normal Mode phase, serial data in the Shift Register is transferred to the respective Output Latch when LE/MOD/CA is high; the data is latched inside the Output Latch when LE/MOD/CA goes low. If the data in the Output Latch is "1" (High), the respective output channel will be enabled after $\overline{OE}$ /SW is pulled down to low. <b>Mode selection input terminal:</b> in the Mode Switching phase, LE/MOD/CA couldn't strobe serial data but its level is used for determining the next mode to which MBI5170 is going to switch. When LE/MOD/CA is high, the next mode is the Current Adjust Mode; when low, the next mode is the Normal Mode. <b>Configuration data strobe input terminal:</b> in the Current Adjust Mode phase, serial data is latched into the Configuration Latch, instead of the Output Latch in the Normal Mode. The serial data here is regarded as the Configuration Code, which affect the output current level of all channels. (See <b>Operation Principle</b> )
5-12	$\overline{OUT0} \sim \overline{OUT7}$	Constant current output terminals
13	OE/SW	Output enable terminal: no matter in what phase MBI5170 operates, the signal $\overline{OE}$ /SW can always enable output drivers to sink current. When its level is (active) low, the output drivers are enabled; when high, all output drivers are turned OFF (blanked). Mode switching trigger terminal: a one-clock-wide short signal pulse of $\overline{OE}$ /SW could put MBI5170 into the Mode Switching phase. (See Operation Principle)
14	SDO	Serial-data output to the following SDI of next driver IC
15	R-EXT	Input terminal used to connect an external resister for setting up all output current
16	VDD	Supply voltage terminal

In MRI5170 the relationship between	the functions of nin 4 and	13 and the operation phases is listed below:
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Pin No.	Pin Name	Function	Normal Mode	Mode Switching	Current Adjust Mode
LE	LE: latching serial data into the Output Latch	Yes	No	No	
4	LE/MOD/CA	MOD: mode selection	No	Yes	No
		CA: latching serial data into the Configuration Latch	No	No	Yes
13	OF /SW	$\overline{OE}$ : enabling the current output drivers	Yes	Yes	Yes
.0	02,000	SW: entering the Mode Switching phase	Yes	Yes	Yes

#### **Block Diagram**



### **Equivalent Circuits of Inputs and Outputs**



LE/MOD/CA Terminal





CLK, SDI Terminal



**SDO Terminal** 



#### **Timing Diagram**

#### Normal Mode



#### Truth Table (In Normal Mode)

CLK	LE/MOD/CA	OE /SW	SDI	SDI OUT0 OUT5 OUT 7	
	Н	L	D <sub>n</sub>	$\overline{Dn} \dots \overline{Dn - 5} \dots \overline{Dn - 7}$	D <sub>n-7</sub>
	L	L	D <sub>n+1</sub>	No Change	D <sub>n-6</sub>
	Н	L	D <sub>n+2</sub>	$\overline{Dn+2}$ $\overline{Dn-3}$ $\overline{Dn-5}$	D <sub>n-5</sub>
	х	L	D <sub>n+3</sub>	$\overline{Dn+2}$ $\overline{Dn-3}$ $\overline{Dn-5}$	D <sub>n-5</sub>
	х	Н	D <sub>n+3</sub>	Off	D <sub>n-5</sub>

# MBI51708-Bit Constant Current LED Sink Driver with Gain ControlSwitching to Current Adjust Mode



The above shows an example of the signal sequence that can set the next operation mode of MBI5170 to be the Current Adjust Mode. The LE/MOD/CA active pulse here would not latch any serial data.

## Writing Configuration Code (In Current Adjust Mode)



In the Current Adjust Mode, by sending the positive pulse of LE/MOD/CA, the content of the Shift Register with a Configuration Code will be written to the 8-bit Configuration Latch.

#### Switching to Normal Mode



The above signal sequence example can make MBI5170 resume to the Normal Mode.

#### Note:

If users want to know the whole process, that is how to enter the Current Adjust Mode, write the Configuration Code, and resume to the Normal Mode, please refer to the section **Operation Principle**.

## **Maximum Ratings**

Character	Symbol	Rat	ing	Unit		
Supply Voltage			V <sub>DD</sub>	0 ~ 7.0		V
Input Voltage			V <sub>IN</sub>	-0.4 ~ V	<sub>DD</sub> + 0.4	V
Output Current			I <sub>OUT</sub>	+1	20	mA
Output Voltage			V <sub>DS</sub>	-0.5 ~	- +20	V
Clock Frequency			F <sub>CLK</sub>	2	5	MHz
GND Terminal Current			I <sub>GND</sub>	10	00	mA
	CN	GN		1.55	1.66	
Power Dissipation	CD	GD	- P <sub>D</sub> -	1.17	1.43	w
(On PCB, Ta=25°C)	CDW	GDW		1.62	1.46	vv
	СР	GP		1.05	1.25	
	CN	GN		64.35	60.20	
Thermal Resistance	CD	GD		85.82	70.14	°0444
(On PCB, Ta=25°C)	CDW	GDW	R <sub>th(j-a)</sub>	61.63	68.67	°C/W
	СР	GP		94.91	80.00	
Operating Temperature			T <sub>opr</sub>	-40 ~ +85		°C
Storage Temperature			T <sub>stg</sub>	-55 ~	+150	°C

#### **Recommended Operating Conditions**

Characteristics	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply Voltage	V <sub>DD</sub>	-	4.5	5.0	5.5	V
Output Voltage	V <sub>DS</sub>	OUT0~OUT7	-	-	17.0	V
	I <sub>OUT</sub>	$\overline{OUT0} \sim \overline{OUT7}$ , CM*=1, V <sub>DD</sub> =5V	10	-	120	mA
Output Current	I <sub>OUT</sub>	$\overline{OUT0} \sim \overline{OUT7}$ , CM*=0, V <sub>DD</sub> =5V	5	-	40	mA
	I <sub>OH</sub>	SDO	-	-	-1.0	mA
	I <sub>OL</sub>	SDO	-	-	5.5 17.0 120 40	mA
Input Voltage	V <sub>IH</sub>	CLK, OE/SW, LE/MOD/CA, and SDI	0.7V <sub>DD</sub>	-	V <sub>DD</sub> +0.3	V
input voitage	V <sub>IL</sub>	CLK, OE/SW, LE/MOD/CA, and SDI	-0.3	-	0.3V <sub>DD</sub>	V
CLK Pulse Width	t <sub>w(CLK)</sub>		20	-	-	ns
Setup Time for SDI	t <sub>su(D)</sub>		5	-	-	ns
Hold Time for SDI	t <sub>h(D)</sub>	-	10	-	-	ns
LE/MOD/CA Pulse Width	t <sub>w(L)</sub>		20	-	-	ns
Setup Time for LE/MOD/CA	t <sub>su(L)</sub>		5	-	-	ns
Hold Time for LE/MOD/CA	t <sub>h(L)</sub>	Current Adjust Mode	10	-	-	ns
Setup Time for LE/MOD/CA	t <sub>su(MOD)</sub>	In Mada Switching	5	-	-	ns
Hold Time for LE/MOD/CA	t <sub>h(MOD)</sub>		10	-	-	ns
	t <sub>w(SW)</sub>	To trigger Mode Switching	20	-	-	ns
OE /SW Pulse Width	t <sub>w(OE)</sub>	I <sub>out</sub> < 60mA	200	-	-	ns
	t <sub>w(OE)</sub>	I <sub>out</sub> = 60~100mA	400	-   -   17.0     10   -   120     5   -   40     -   -   1.0     -   -   1.0 $7V_{DD}$ - $V_{DD}+0.3$ 0.3   - $0.3V_{DD}$ 20   -   -     5   -   -     10   -   -     20   -   -     5   -   -     10   -   -     5   -   -     10   -   -     20   -   -     5   -   -     10   -   -     20   -   -     5   -   -     10   -   -     200   -   -     200   -   -     200   -   -     200   -   -     200   -   -     200   -   -     200   -   -	ns	
Setup Time for $\overline{OE}$ /SW	t <sub>su(SW)</sub>	To trigger Mode	5	-	-	ns
Hold Time for $\overline{OE}$ /SW	t <sub>h(SW)</sub>	$\overline{OUT0} \sim \overline{OUT7}$ , $CM*=1, V_{DD} = 5V$ 10 $\overline{OUT0} \sim \overline{OUT7}$ , $CM*=0, V_{DD} = 5V$ 5 $\overline{SDO}$ - $\overline{SDO}$ - $\overline{SDO}$ - $\overline{CLK}, \overline{OE} / SW$ , $LE/MOD/CA, and SDI$ $0.7V_{DE}$ $\overline{CLK}, \overline{OE} / SW$ , $LE/MOD/CA, and SDI-0.3\overline{CLK}, \overline{OE} / SW,LE/MOD/CA, and SDI-0.3\overline{CLK}, \overline{OE} / SW,LE/MOD/CA, and SDI-0.3\overline{CLK}, \overline{OE} / SW,LE/MOD/CA, and SDI-0.3\overline{CUK}, \overline{OE} / SW,Normal Mode andCurrent Adjust Mode10\overline{OUK}, \overline{OE} / SW-0.3\overline{OUK}, \overline{OUK}, O$	10	-	-	ns
Clock Frequency	F <sub>CLK</sub>	•	-	_	25.0	MHz

\* CM is one bit in configuration code and called as "Current Multiplier." It would affect the ratio of  $I_{OUT}$  to  $I_{rext}$ . The detail information could be found in the section **Operation Principle**.

## **Electrical Characteristics (V<sub>DD</sub> = 5.0V)**

Charact	eristics	Symbol	Condition		Min.	Тур.	Max.	Unit
Supply Voltag	е	V <sub>DD</sub>		-	4.5	5.0	5.5	V
Output Voltag	e	V <sub>DS</sub>	OUTO~ OUT7		-	-	17.0	V
		I <sub>OUT</sub>	OUTO~ OUT7, O	CM= 1	10	-	120	mA
Output Current		I <sub>OUT</sub>	OUTO~ OUT7, O	CM= 0	5	-	40	mA
		I <sub>ОН</sub>	SDO		-	I	-1.0	mA
		I <sub>OL</sub>	SDO Fa = -40~85°C (		-	I	1.0	mA
Input Voltage	"H" level	V <sub>IH</sub>			$0.7V_{\text{DD}}$	I	$V_{\text{DD}}$	V
input voitage	"L" level	VIL	Га = -40∼85°C		GND	I	$0.3V_{\text{DD}}$	V
Output Leaka	ge Current		$V_{\text{DS}}$ =17.0V and ch	annel off	-	-	0.5	μA
Output Voltag	e SDO	V <sub>OL</sub>	I <sub>OL</sub> =+1.0mA		-	-	0.4	V
	e 300	V <sub>OH</sub>	I <sub>OH</sub> =-1.0mA		4.6	-	-	V
Output Currer	nt 1	I <sub>OUT1</sub>	V <sub>DS</sub> = 0.5V; R <sub>ext</sub> = VG** = 0.992; CM	744Ω; 1 = 1	-	25.0	-	mA
Current Skew (between cha		dl <sub>out1</sub>	$\begin{array}{l} I_{\text{OUT}} = 25 m A \\ V_{\text{DS}} \geq 0.5 V \end{array}$	R <sub>ext</sub> =744 Ω	-	±1	±3	%
Output Currer	it 2	I <sub>OUT2</sub>	V <sub>DS</sub> = 0.6V; R <sub>ext</sub> = VG** = 0.992; CM	372Ω; 1 = 1	-	50.0	-	mA
Current Skew (between cha		dl <sub>out2</sub>	I <sub>OUT</sub> = 50mA V <sub>DS</sub> ≥ 0.6V	$I_{OUT} = 50 \text{mA}$ R = 372 O		±1	±3	%
Output Currer	it 3	I <sub>OUT3</sub>	V <sub>DS</sub> = 0.8V; R <sub>ext</sub> = VG** = 0.992; CM		-	100	-	mA
Current Skew (between cha	nnels)	dl <sub>out3</sub>	I <sub>OUT</sub> = 100mA V <sub>DS</sub> ≥0.8V	R <sub>ext</sub> =186 Ω	-	±1	±3	%
Output Currer Output Voltag		%/dV <sub>DS</sub>	V <sub>DS</sub> within 1.0V ar	nd 3.0V	-	±0.1	-	% / V
Output Currer Supply Voltag	it vs.	%/dV <sub>DD</sub>	V <sub>DD</sub> within 4.5V ar	nd 5.5V	-	+0.5	-	% / V
Pull-up Resist		R <sub>IN</sub> (up)	OE /SW		250	500	800	KΩ
Pull-down Re	sistor	R <sub>IN</sub> (down)	LE/MOD/CA		250	500	800	KΩ
		I <sub>DD</sub> (off) 0	R <sub>ext</sub> =Open, <u>OUT0</u> ~ CM = 1, VG= 0.99		-	2.85	3.65	
	" <b>066</b> "	I <sub>DD</sub> (off) 1	R <sub>ext</sub> =744 Ω, <u>OUT0</u> ~ CM = 1, VG= 0.99	~ OUT7 =Off;	-	5.9	7.9	
	"OFF"	I <sub>DD</sub> (off) 2	R <sub>ext</sub> =372 Ω, <u>OUT0</u> ~ CM = 1, VG= 0.99	- OUT7 =Off;	-	8.7	10.7	
Supply Current		I <sub>DD</sub> (off) 3	R <sub>ext</sub> =186 Ω, <u>OUTO</u> ~ CM = 1, VG= 0.99	- OUT7 =Off;	-	14.4	16.4	mA
		I <sub>DD</sub> (on) 1	$R_{ext}$ =744 Ω, $\overline{OUTO}$ ~ CM = 1, VG= 0.99	~ OUT7 =On;	-	5.8	7.8	
	"ON"	I <sub>DD</sub> (on) 2	$R_{ext}$ =372 Ω, $\overline{OUTO}$ ~ CM = 1, VG= 0.99	~ OUT7 =On;	-	8.7	10.7	
		I <sub>DD</sub> (on) 3	$R_{ext}$ =186 Ω, $\overline{OUT0}$ ~ CM = 1, VG= 0.99	~ OUT7 =On;	-	13.5	15.5	

\*\* In the above table, VG is the programmable gain of the voltage at the terminal R-EXT. The detail description could be found in the section **Operation Principle**.

# **Electrical Characteristics (V\_{DD} = 3.3V)**

Charact	eristics	Symbol Condition		Min.	Тур.	Max.	Unit	
Supply Voltage	e	V <sub>DD</sub>	-		3.0	3.3	3.6	V
Output Voltage	e	V <sub>DS</sub>			-	-	17.0	V
			OUT0~ OUT7, CM=	-1,	10	-	120	mA
Output Current		I <sub>OUT</sub>	OUTO~ OUT7, CM=	=0,	5	-	40	mA
		I <sub>OH</sub>	SDO		-	-	-1.0	mA
		I <sub>OL</sub>	SDO		-	-	1.0	mA
Input Voltage	"H" level	V <sub>IH</sub>			$0.7V_{\text{DD}}$	-	$V_{\text{DD}}$	V
input voitage	"L" level	V <sub>IL</sub>	Ta = -40~85°C		GND	-	$0.3V_{\text{DD}}$	V
Output Leakag	ge Current		$V_{DS}$ =17.0V and chann	el off	-	-	0.5	μA
Output Voltage	e SDO	V <sub>OL</sub>	I <sub>OL</sub> =+1.0mA		-	-	0.4	V
	300	V <sub>OH</sub>	I <sub>OH</sub> =-1.0mA		2.9	-	-	V
Output Curren	t 1	I <sub>OUT1</sub>	V <sub>DS</sub> = 0.5V; R <sub>ext</sub> = 744 VG = 0.992; CM = 1	·Ω;	-	25.0	-	mA
Current Skew (between char	nels)	dl <sub>out1</sub>	$\begin{array}{l} I_{OUT} = 25 mA \\ V_{DS} \geq 0.5 V \end{array}$	I <sub>OUT</sub> = 25mA R = 744 O		±1	±3	%
Output Curren	t 2	I <sub>OUT2</sub>	V <sub>DS</sub> = 0.6V; R <sub>ext</sub> = 372 VG = 0.992; CM = 1	2Ω;	-	50.0	-	mA
Current Skew (between char	nels)	dl <sub>OUT2</sub>	I = 50mA	R <sub>ext</sub> =372 Ω	-	±1	±3	%
Output Curren Output Voltage		%/dV <sub>DS</sub>	$V_{DS}$ within 1.0V and 3	.0V	-	±0.1	-	% / V
Output Curren Supply Voltage	t vs.	%/dV <sub>DD</sub>	$V_{\text{DD}}$ within 3.2V and 3	.6V	-	±1	-	% / V
Pull-up Resiste		R <sub>IN</sub> (up)	OE /SW		250	500	800	KΩ
Pull-down Res	istor	R <sub>IN</sub> (down)	LE/MOD/CA		250	500	800	KΩ
		I <sub>DD</sub> (off) 0	R <sub>ext</sub> =Open, <u>OUT0</u> ~ <u>OUT</u> CM = 1, VG= 0.992	77 <b>=</b> Off;	-	0.78	1.58	
	"OFF"	I <sub>DD</sub> (off) 1	R <sub>ext</sub> =744 Ω, <u>OUT0</u> ~ <u>OU</u> CM = 1, VG= 0.992	⊤7 =Off;	-	3.6	4.4	
Supply Current		$I_{DD}(off) 2 \begin{array}{c} R_{ext}=372 \ \Omega, \ \overline{OUT0} \sim \overline{OUT7} = Off; \\ CM = 1, \ VG = 0.992 \end{array}$		⊤7 =Off;	-	6.5	7.3	mA
	" <b>O</b> NI"	I <sub>DD</sub> (on) 1	$R_{ext}=744 \Omega, \overline{OUT0} \sim \overline{OUT7} = On;$ CM = 1, VG= 0.992		-	3.6	4.2	
	"ON"	I <sub>DD</sub> (on) 2	R <sub>ext</sub> =372 Ω, <u>OUTO</u> ~ <u>OU</u> CM = 1, VG= 0.992	⊤7 =On;	-	6.4	7.2	

# Switching Characteristics ( $V_{DD}$ = 5.0V)

Cha	racteristics	Symbol	Condition	Min.	Тур.	Max.	Unit
	CLK - OUTn	t <sub>pLH1</sub>		-	100	150	ns
Time ("L" to "H") Propagation Delay Time ("H" to "L")	LE/MOD/CA-OUTn	t <sub>pLH2</sub>		-	100	150	ns
Time ("L" to "H")	OE /SW - OUTn	t <sub>pLH3</sub>		-	100	150	ns
	$ \begin{array}{c} \mbox{CLK} - \overline{\mbox{OUTn}} & \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	t <sub>pLH</sub>	Test Oberit for	20	25	30	ns
	CLK - OUTn	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	100	150	ns		
	LE/MOD/CA - OUTn	t <sub>pHL2</sub>	Characteristics $V_{DD}$ =5.0 V $V_{DS}$ =0.8 V $V_{IH}$ =V <sub>DD</sub> $V_{IL}$ =GND	-	100	150	ns
	OE/SW - OUTn	t <sub>pHL3</sub>		-	100	150	ns
	CLK - SDO	t <sub>pHL</sub>		20	25	30	ns
Time ("L" to "H") Propagation Delay Time ("H" to "L") Pulse Width Hold Time for LE/M Setup Time for LE/M Maximum CLK Rise Maximum CLK Fall	CLK	t <sub>w(CLK)</sub>		20	-	-	ns
	LE/MOD/CA	t <sub>w(L)</sub>		20	-	-	ns
	OE /SW (@lout< 60mA)	t <sub>w(OE)</sub>	R <sub>L</sub> =64 Ω	200	-	-	ns
Pulse Width LE/MOD/CA   OE /SW (@lout< 60mA)		t <sub>h(L)</sub>		10	-	-	ns
Setup Time for LE/	MOD/CA	t <sub>su(L)</sub>		5	-	-	ns
Maximum CLK Rise	Time	t <sub>r</sub> ***		-	-	500	ns
Maximum CLK Fall	Time	t <sub>f</sub> ***		-	-	500	ns
Output Rise Time o	f Vout (turn off)	t <sub>or</sub>		-	120	150	ns
Output Fall Time of	Vout (turn on)	t <sub>of</sub>		-	200	250	ns
Clock Frequency		F <sub>CLK</sub>	Cascade Operation	-	-	25.0	MHz

\*\*\* If MBI5170 are connected in cascade and t<sub>r</sub> or t<sub>f</sub> is large, it may be critical to achieve the timing required for data transfer between two cascaded LED drivers MBI5170.

# Switching Characteristics ( $V_{DD}$ = 3.3V)

Cha	racteristics	Symbol	Condition	Min.	Тур.	Max.	Unit
	CLK - OUTn	t <sub>pLH1</sub>		-	100	150	ns
Propagation Delay Time ("L" to "H") Propagation Delay Time ("H" to "L") Pulse Width Hold Time for LE/M Setup Time for LE/ Maximum CLK Rise Maximum CLK Fall Output Rise Time o	LE/MOD/CA - OUTn	t <sub>pLH2</sub>		-	100	150	ns
Time ("L" to "H")	OE /SW - OUTn	t <sub>pLH3</sub>	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	150	ns		
	CLK - SDO	t <sub>pLH</sub>	Test Oberit for	45	55	)   150     )   150     )   150     )   65     )   200     )   200     )   200     )   200     )   200     )   200     )   200     )   200     )   200     )   500     )   500     )   150	ns
	CLK - OUTn	t <sub>pHL1</sub>		-	130	150     150     150     65     200     200     200     200     200     200     200     200     200     200     200     200     500     500     150     400	ns
Propagation Delay Time ("L" to "H") Propagation Delay Time ("H" to "L") Pulse Width Hold Time for LE/M Setup Time for LE/I Maximum CLK Rise Maximum CLK Fall Dutput Rise Time of Dutput Fall Time of	LE/MOD/CA - OUTn	t <sub>pHL2</sub>	Characteristics	-	130	200	ns
Time ("H" to "L")	OE/SW - OUTn	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	200	ns			
	CLK - SDO	t <sub>pHL</sub>		45	55	65	ns
Propagation Delay Time ("L" to "H") Propagation Delay	CLK	t <sub>w(CLK)</sub>	V <sub>IL</sub> =GND	20	-	-	ns
	LE/MOD/CA	t <sub>w(L)</sub>		20	-	-	ns
	OE /SW (@I <sub>OUT</sub> < 60mA)	t <sub>w(OE)</sub>	R <sub>L</sub> =64 Ω	200	-	-	ns
Hold Time for LE/M	OD/CA	t <sub>h(L)</sub>		10	-	-	ns
Setup Time for LE/	MOD/CA	t <sub>su(L)</sub>		5	-	-	ns
Maximum CLK Rise	e Time	t <sub>r</sub>		-	-	500	ns
Maximum CLK Fall	Time	t <sub>f</sub>		-	-	500	ns
Output Rise Time o	f Vout (turn off)	t <sub>or</sub>		-	120	150	ns
Output Fall Time of	Vout (turn on)	t <sub>of</sub>		-	200	400	ns
Clock Frequency		F <sub>CLK</sub>		-	-	12.0	MHz

# Test Circuit for Electrical Characteristics



## Test Circuit for Switching Characteristics



## **Timing Waveform**

Normal Mode and Current Adjust Mode





50% t<sub>pHL3</sub> 90% 50% 50% 50% 50% 50% 50% t<sub>or</sub>

# MBI51708-Bit Constant Current LED Sink Driver with Gain ControlSwitching to Current Adjust Mode



## **Operation Principle**

#### **Constant Current**

- In LED display applications, MBI5170 provides nearly no current variations from channel to channel and from IC to IC. This can be achieved by:
- 1) While  $I_{OUT} \leq 100$  mA, the maximum current skew between channels is less than ±3%, and that between IC's is less than ±6%.
- 2) In addition, the characteristics curve of output stage in the saturation region is flat and users can refer to the output characteristics figure as shown below. Thus, the output current can be kept constant regardless of the variations of LED forward voltage (Vf).



### MBI5170 8-Bit Constant Current LED Sink Driver with Gain Control Adjusting Output Current

MBI5170 scales up the reference current  $I_{ref}$  set by the external resistor  $R_{ext}$  to sink a current  $I_{out}$  at each output port. Users can follow the below formulas to calculate the output current  $I_{out}$  in the saturation region:

V<sub>R-EXT</sub> = 1.25Volt x VG

 $I_{rext} = V_{R-EXT} / R_{ext}$  if another end of the external resistor  $R_{ext}$  is connected to ground.

I<sub>out</sub> = I<sub>rext</sub> x 15 x 3<sup>(CM-1)</sup>

where  $R_{ext}$  is the resistance of the external resistor connected to the R-EXT terminal, and  $V_{R-EXT}$  is the voltage of the R-EXT terminal and controlled by the programmable voltage gain VG, which is defined by the Configuration Code. The Current Multiplier CM would determine that the ratio  $I_{out}/I_{rext}$  is 15 or 5. After power-on, the default value of VG is 127/128 = 0.992 and the default value of CM is 1, so that the ratio  $I_{out}/I_{rext}$  is 15. Based on the default VG and CM,

V<sub>R-EXT</sub> = 1.25Volt x 127/128= 1.24Volt

I<sub>out</sub> = (1.24Volt / R<sub>ext</sub> ) x 15

Hence, the default magnitude of current is around 50mA at 372 $\Omega$  and 25mA at 744 $\Omega$ . The default relationship after power-on between  $I_{out}$  and  $R_{ext}$  is shown in the following figure.



#### Operation Phases

MBI5170 exploits the **Share-I-O**<sup>TM</sup> technique to extend the functionality of pins in MBI5168 in order to provide run-time programmable LED driving current in the Current Adjust Mode phase as well as the original function of MBI5168 in the Normal Mode phase. In order to switch between the two modes, MBI5170 monitors the signal  $\overline{OE}$  /SW. Once a one-clock-wide pulse of  $\overline{OE}$  /SW appears, MBI5170 would enter the two-clock-period transition phase---the Mode Switching phase. After power-on, the default operation mode is the Normal Mode.

## **Operation Mode Switching**



As shown in the above figures, once a one-clock-wide short pulse "**101**" of  $\overline{OE}$  /SW appears, MBI5170 would enter the Mode Switching phase. At the 4<sup>th</sup> rising edge of CLK, if LE/MOD/CA is sampled as "Voltage High", MBI5170 would switch to the Current Adjust Mode; otherwise, it would switch to the Normal Mode. Worthwhile noticing, the signal LE/MOD/CA between the 3<sup>rd</sup> and the 5<sup>th</sup> rising edges of CLK can not latch any data. Its level is just used for determining which mode to switch. However, the short pulse of  $\overline{OE}$  /SW can still enable the output ports. During the mode switching, the serial data can still be transferred through the pin SDI and shifted out from the pin SDO. Note:

- The signal sequence for the mode switching could be frequently used for making sure under which mode MBI5170 is working.
- 2. The aforementioned "1" and "0" are sampled at the rising edge of CLK. The "X" means its level would not affect the result of mode switching mechanism.

#### Normal Mode Phase

MBI5170 in the Normal Mode phase has similar functionality to MBI5168. The only difference is short pulse  $\overline{OE}$  /SW signal monitoring. The short pulse would trigger MBI5170 to switch its operation mode. However, as long as the signal LE/MOD/CA is not Voltage High in the Mode Switching phase, MBI5170 would still remain in the Normal Mode as if no mode switching occurs.

# MBI51708-Bit Constant Current LED Sink Driver with Gain ControlCurrent Adjust Mode Phase and Writing Configuration Code



In the Current Adjust Mode phase, the serial data could be transferred into MBI5170 via the pin SDI, shifted in the Shift Register, and go out via the pin SDO. The active low signal  $\overline{OE}$ /SW can enable the output drivers to sink current. These are the same as those in the Normal Mode. The difference is that the active high signal LE/MOD/CA latches the serial data in the Shift Register to the Configuration Latch, instead of the Output Latch. The latched serial data is regarded as the Configuration Code. The code would be memorized until power off or the Configuration Latch is re-written. As shown above, the timing for writing the Configuration Code is the same as that in the Normal Mode for latching output channel data.

### 8-Bit Configuration Code and Current Gain CG

	Bit Definition of 8-Bit Configuration Code							
	Bit 0	Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	Bit 7
Meaning	СМ	HC	CC0	CC1	CC2	CC3	CC4	CC5
Default Value	1	1	1	1	1	1	1	1

Bit definition of the Configuration Code in the Configuration Latch is shown above. Bit 7 is first sent into MBI5170 via the pin SDI. Bit 1 ~ 7, {HC, CC[0:5]}, would determine the voltage gain (VG), that affects the voltage at R-EXT terminal and indirectly the reference current  $I_{rext}$  flowing through the external resistor at terminal R-EXT. Bit 0 is the Current Multiplier (CM) bit, that determines the ratio  $I_{out}/I_{rext}$ . Each combination of VG and CM would give a Current Gain (CG).

• VG: the relationship between {HC,CC[0:5]} and the Voltage Gain G can be formulated as below:

 $VG = (1 + HC) \times (1 + D/64) / 4$ 

 $D = CC0 \times 2^{5} + CC1 \times 2^{4} + CC2 \times 2^{3} + CC3 \times 2^{2} + CC4 \times 2^{1} + CC5 \times 2^{0}$ 

where HC is 1 or 0, and D is the binary value of CC[0:5]. So, the VG could be regarded as a floating-point number with one bit exponent HC and 6-bit mantissa CC[0:5]. {HC,CC[0:5]} divides the programmable voltage gain VG into 128 steps and two sub-bands:

Low voltage sub-band (HC=0): VG =  $1/4 \sim 127/256$ , linearly divided into 64 steps; High voltage sub-band (HC=1): VG =  $1/2 \sim 127/128$ , linearly divided into 64 steps, too.

 CM: as well as determining the ratio I<sub>out</sub>/I<sub>rext</sub>, the CM bit would limit the output current range. High Current Multiplier (CM=1): I<sub>out</sub>/I<sub>rext</sub> = 15 and suitable for output current range I<sub>out</sub> = 10 ~ 120mA. Low Current Multiplier (CM=0): I<sub>out</sub>/I<sub>rext</sub> = 5 and suitable for output current range I<sub>out</sub> = 5 ~ 40mA.

• CG: the total Current Gain is defined as the following.

V<sub>R-EXT</sub> = 1.25Volt \* VG

 $I_{rext} = V_{R-EXT} / R_{ext}$  if another end of the external resistor  $R_{ext}$  is connected to ground.

I<sub>out</sub> = I<sub>rext</sub> \* 15 \* 3<sup>(CM-1)</sup> = 1.25Volt / R<sub>ext</sub> \* VG \* 15 \* 3<sup>(CM-1)</sup> = (1.25Volt / R<sub>ext</sub> \* 15) \* CG

We define CG = VG \*  $3^{(CM-1)}$ . Hence CG =  $(1/12) \sim (127/128)$  and it is divided into 256 steps, totally. If

CG = 127/128 = 0.992, the I<sub>out</sub>-R<sub>ext</sub> relationship is similar to that in MBI5168.

For example,

a) When the Configuration Code {CM, HC, CC[0:5]} = {1,1,11111},

b) When the Configuration Code is {1,1,000000},

c) When the Configuration Code is {0,0,000000},

VG = (1+0)\*(1+ 0/64)/4 = 1/4; and CG = (1/4)\*3^-1 = 1/12

After power on, the default value of the Configuration Code {CM, HC, CC[0:5]} is  $\{1,1,11111\}$ . Thus, VG = CG = 0.992. The relationship between the Configuration Code and the Current Gain CG is shown in the following.



Current Gain CG v.s. Configuration Code in Binary Format

#### **Timing Chart for Current Adjust Mode (An Example)**



## **Application Information**

### Soldering Process of "Pb-free & Green" Package Plating\*

Macroblock has defines "Pb-Free & Green" to mean semiconductor products that are compatible with the current RoHS requirements and selected **100% pure tin** (Sn) to provide forward and backward compatibility with both the current industry-standard SnPb-based soldering processes and higher-temperature Pb-free processes. Pure tin is widely accepted by customers and suppliers of electronic devices in Europe, Asia and the US as the lead-free surface finish of choice to replace tin-lead. Also, it is backward compatible to standard 215°C to 240°C reflow processes which adopt tin/lead (SnPb) solder paste. However, in the whole Pb-free soldering processes and materials, 100% pure tin (Sn), will all require up to 260°C for proper soldering on boards, referring to J-STD-020B as shown below.



\*Note1: For details, please refer to Macroblock's "Policy on Pb-free & Green Package".

## Package Power Dissipation (P<sub>D</sub>)

The maximum allowable package power dissipation is determined as  $P_D(max) = (Tj - Ta) / R_{th(j-a)}$ . When 8 output channels are turned on simultaneously, the actual package power dissipation is

 $P_{D}(act) = (I_{DD} \times V_{DD}) + (I_{OUT} \times Duty \times V_{DS} \times 8)$ 

Therefore, to keep  $P_D(act) \le P_D(max)$ , the allowable maximum output current as a function of duty cycle is

 $I_{OUT} = \{ [ (Tj - Ta) / R_{th(j-a)}] - (I_{DD} \times V_{DD}) \} / V_{DS} / Duty / 8 \}$ 

where Tj = 150°C.





<b>Condition</b> : $V_{DS}$ = 1.0V, $V_{DD}$ = 5.0V, 8 output channels active, Ta is listed in the legend below.					
Device Type R <sub>th(j-a)</sub> (°C/W		C/W)	Note		
CN	GN	64.35	60.20		
CD	GD	85.82	70.14	<b>───</b> 25℃	
CDW	GDW	61.63	68.67	55℃	
CP	GP	94.91	80.00	85℃	

# MBI51708-Bit Constant Current LED Sink Driver with Gain ControlLoad Supply Voltage (VLED)

Considering the package power dissipating limits, users had better apply MBI5170 to operate within  $V_{DS} = 0.4V \sim 1.0V$ . If  $V_{LED}$  is higher, for instance, than 5V,  $V_{DS}$  may be so high that  $P_{D(act)} > P_{D(max)}$ , where  $V_{DS} = V_{LED} - V_F$ . In this case, it is recommended to use as low supply voltage as possible or to arrange a voltage reducer,  $V_{DROP}$ . The voltage reducer lets  $V_{DS} = (V_{LED} - V_F) - V_{DROP}$ . Resistors or Zener diodes can be used as the reducers in the applications as shown in the following figures.



## Switching Noise Reduction

LED Driver ICs are frequently used in switch-mode applications which always behave with switching noise due to parasitic inductance on PCB. To eliminate switching noise, refer to "Application Note for 8-bit and 16-bit LED Drivers- Overshoot".

#### **Outline Drawings**







MBI5170CD\GD Outline Drawing



MBI5170CDW\GDW Outline Drawing



MBI5170CP\GP Outline Drawing

Note: The unit for the outline drawing is mm.

#### Product Top-mark Information



#### **Product Revision History**

Datasheet version	Device version code
VA.00	Not defined
VA.02	A

#### **Product Ordering Information**

Part Number	Package Type	Weight (g)
MBI5170CN	P-DIP16-300-2.54	1.02
MBI5170CD	SOP16-150-1.27	0.13
MBI5170CDW	SOP16-300-1.27	0.37
MBI5170CP	SSOP16-150-0.64	0.07

Part Number	"Pb-free & Green" Package Type	Weight (g)
MBI5170GN	P-DIP16-300-2.54	1.02
MBI5170GD	SOP16-150-1.27	0.13
MBI5170GDW	SOP16-300-1.27	0.37
MBI5170GP	SSOP16-150-0.64	0.07